

Fig. 11-14 (a) Emitter follower. (b) High-frequency equivalent circuit of emitter follower.

**Single-pole Solution** We can obtain a very simple approximate expression for the transfer function by applying Miller's theorem to the circuit of Fig. 11-14b. With  $K \equiv V_o/V_i$  we obtain the circuit of Fig. 11-15. The low-frequency gain of an emitter follower is close to unity:  $K \approx 1$  and  $1 - K \approx 0$ . Hence the input time constant  $\tau_i \approx (R_s + r_{be})C_c$ . The output time constant  $\tau_o$  is proportional to  $C_L$ , and since we have assumed that the load is highly capacitive, then  $\tau_o \gg \tau_i$ . Hence the upper 3-dB frequency is determined, to a good approximation, by the output circuit alone. Using  $K = 1$ , we obtain

$$V_o = \frac{g_m V_{be}}{1/R_L + j\omega C_L} = \frac{g_m R_L (V_i - V_o)}{1 + j\omega C_L R_L} \quad (11-58)$$

Solving for  $V_o/V_i = K$ , we obtain

$$K = \frac{g_m R_L}{1 + g_m R_L} \frac{1}{1 + j\omega C_L R_L} = \frac{1}{1 + j\omega C_L R_L} \quad (11-59)$$

where

$$K_o \equiv \frac{g_m R_L}{1 + g_m R_L} \approx 1 \quad (11-60)$$

and

$$f_H \equiv \frac{1 + g_m R_L}{2\pi C_L R_L} \approx \frac{g_m}{2\pi C_L} = \frac{f_T C_e}{C_L} \quad (11-61)$$

and  $f_T$  is given by Eq. (11-30). Since  $f_H = 1/2\pi\tau_o$ , we see that  $\tau_o = C_L/g_m$ , and the condition  $\tau_o \gg \tau_i$  requires

$$C_L \gg g_m(R_s + r_{bb'})C_c \quad (11-62)$$

For the parameter values in Fig. 11-14 and  $g_m = 50$  mA/V, this condition is  $C_L \gg (50)(150)(3) = 23$  pF.

Since the input impedance between terminals  $B'$  and  $C$  is very large compared with  $R_s + r_{bb'}$ , then  $K$  also represents the overall voltage gain  $A_{V_s} \equiv V_e/V_s$ . Incidentally, a somewhat better approximation for  $f_H$  is given in Prob. 11-20, where we find

$$f_H = \frac{g_m + g_{b'e}}{2\pi(C_L + C_e)} \quad (11-63)$$

**Input Admittance** We can find the input admittance (excluding  $r_{bb'}$ ) by referring to Fig. 11-15.

$$Y'_i = \frac{I_b}{V'_i} = j\omega[C_c + (1 - K)C_e] + (1 - K)g_{b'e}$$

Substituting  $K$  from Eq. (11-59) in this equation, we find

$$Y'_i = j2\pi f C_c + (g_{b'e} + j2\pi f C_e) \frac{1 - K_o + jf/f_H}{1 + jf/f_H} \quad (11-64)$$

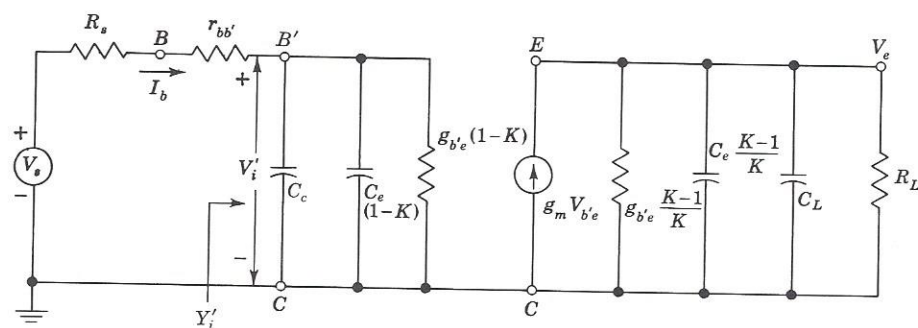


Fig. 11-15 The equivalent circuit of the emitter follower, using Miller's theorem.

Since  $K_o \approx 1$ , the numerator of Eq. (11-64) is affected by frequency at a much lower value of  $f$  than is the denominator. Hence, for  $f < f_H$ , Eq. (11-64) can be written

$$Y_i \approx j2\pi f C_o + (g_{v_e} + j2\pi f C_o) \left( 1 - K_o + \frac{jf}{f_H} \right) \approx j2\pi f [C_o + (1 - K_o)C_o] + g_{v_e} (1 - K_o) + jg_{v_e} \frac{f}{f_H} - 2\pi^2 f^2 \frac{C_o}{f_H} \quad (11-65)$$

where the last term represents a negative resistance which is a function of frequency. Thus, the input impedance consists of a capacitance shunted by a negative resistance and if the source resistance  $R_s$  contains some inductance in series with it, it is possible for the circuit to sustain undesirable oscillations. One way to remedy this condition is to use a small resistance in series with  $R_s$ .

## REFERENCES

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## REVIEW QUESTIONS

- 11-1 Draw the small-signal high-frequency CE model of a transistor.
- 11-2 (a) What is the physical origin of the two capacitors in the hybrid- $\pi$  model? (b) What is the order of magnitude of each capacitance?
- 11-3 What is the order of magnitude of each resistance in the hybrid- $\pi$  model?
- 11-4 How does  $g_m$  vary with (a)  $|I_c|$ ; (b)  $|V_{ce}|$ ; (c)  $T$ ?